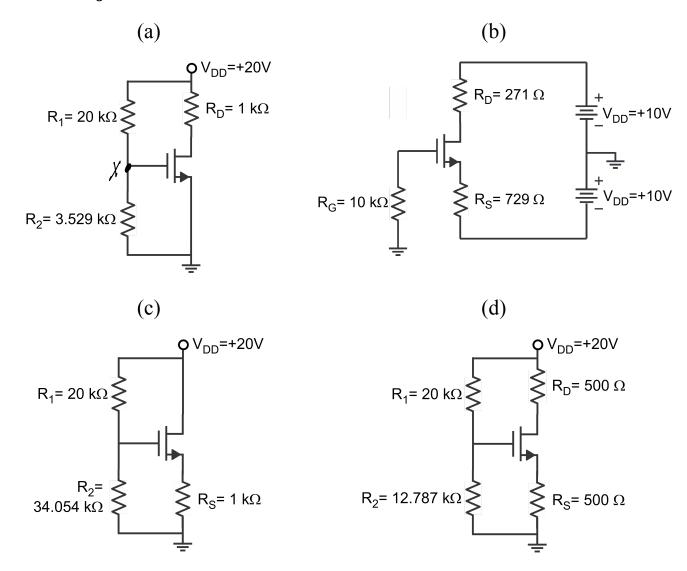
1) For the following four FET circuits, the FET parameters are $V_{TN} = 2.6V$ and $k_N = 0.12 \text{ A/V}^2$. For each circuit, the bias point (Q-point) is the same. You may use an online calculator to solve any quadratic equations.

Find for V_{GS} , V_{DS} , I_{D} . In all cases, verify that the transistor is "on" and operating in a saturated region.



$$V_{00} = 20V$$
 $V_{gS} = 3.529 \times 20 = 2.9997 V$
 $3.529 + 20$

Assume maybet 1s in saturation made:
$$\int_{0}^{\infty} \frac{1}{2} \ln \left[\sqrt{g_{s}} - \sqrt{1}^{2} \right]^{2} = \frac{1}{2} \times 0.12 \left[\frac{2.9997}{2.9997} - \frac{2.6}{2.6} \right]^{2} = 9.56 \text{ m/s}$$

$$-V_{00} + V_{00} + V_{00} = 0$$

 $V_{00} = V_{00} - I_{0}R_{0} = 20 - 9.58 \times 1 = 10.42V$
 $V_{00} \ge v_{00} - v_{00}$
 $V_{00} \ge v_{00} - v_{00}$

$$\int_{0}^{\infty} V_{00} = 10V$$

$$\int_{0}^{\infty} V_{0} + V_{0} + V_{0} = 0$$

$$\int_{0}^{\infty} V_{0} + V_{0} + V_{0} = 0$$

$$\int_{0}^{\infty} V_{0} + V_{0} + V_{0} = 0$$

Assume master in suturation
$$10 = \frac{1}{2} \ln \left[V_{gs} - V_{+} \right]^{2}$$

10
$$-v_{95} = 43.79 v_{95}^2 + 295.68 - 227.45 v_{95}$$

 $43.74 v_{95}^2 - 226.45 v_{95} + 285.68 = 0$
 $v_{95} = 3$ $v_{95} = 2.171$

$$= 7.39$$

$$V_{0S} = V_{0} - V_{S} = 7.39 - (-3) = 10.39 \text{ V}$$

$$|2.59 - Vg_s| = 60 Vg_s^2 - 3 |2 Vg_s| + 405.6$$

 $60 Vg_s^2 - 3 |1 Vg_s| + 393.01 = 0$
 $Vg_s = 2.99V$ $Vg_s = 2.16V$
 $Vg_s > V_t$

$$|_{0} = \frac{12.59 - 2.99}{1} = 9.6 \text{ m/s}$$

$$V_{0S} = V_0 - V_S = 20 - 9.6 = 10.4 v$$
 $V_{0S} \ge V_{9S} - V_{4}$
 $11.4 \ge 2.91 - 2.6$ free

(1)
$$V_g = \frac{12.787}{12.181+20} \times 20 = 7.8V$$